Vishay Semiconductors

High Performance Schottky Rectifier, 1.0 A



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PRODUCT SUMMARY				
Package	SMB			
I _{F(AV)}	1.0 A			
V _R	30 V			
V _F at I _F	0.30 V			
I _{RM} max.	20 mA at 125 °C			
T _J max.	125 °C			
Diode variation	Single die			
E _{AS}	3.0 mJ			

FEATURES

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation



COMPLIANT

HALOGEN

- Guard ring for enhanced ruggedness and long
- Meets MSL level 1, per J-STD-020, LF maximum peak
- of 260 °C
 Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION

The VS-MBRS130L-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	1.0	A	
V _{RRM}		30	V	
I _{FSM}	t _p = 5 μs sine	230	A	
V _F	1.0 A _{pk} , T _J = 125 °C	0.30	V	
TJ	Range	-55 to +125	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-MBRS130L-M3	UNITS	
Maximum DC reverse voltage	V _R	30	V	
Maximum working peak reverse voltage	V _{RWM}	50	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_L = 112 °C, rectangular waveform		1.0	
Maximum peak one cycle	Irou	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	230	А
non-repetitive surge current	IFSM	10 ms sine or 6 ms rect. pulse	V_{RRM} applied	40	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 1 \text{ A}, L = 6 \text{ mH}$ 3.0		3.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s1.0Frequency limited by T _J maximum V _A = 1.5 x V _R typical1.0		А	



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	V _{FM} ⁽¹⁾	1 A	T _J = 25 °C	0.420	
Maximum forward voltage drep		2 A		0.470	V
Maximum forward voltage drop		1 A	- T _J = 125 °C	0.300	
		2 A		0.370	
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	1	
		T _J = 100 °C		10	mA
		T _J = 125 °C		20	
Maximum junction capacitance	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		200	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	T _J ⁽¹⁾		-55 to +125	°C
Maximum storage temperature range	T _{Stg}		-55 to +150	C
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾	DC operation See fig. 4	25	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	C/W
Approvimeto weight			0.10	g
Approximate weight			0.003	oz.
Marking device		Case style SMB (similar to DO-214AA)	13	L

Notes

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$ (1)

(2) Mounted 1" square PCB



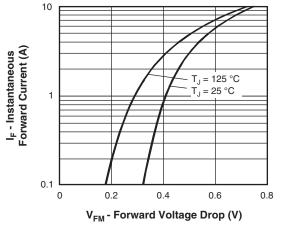


Fig. 1 - Maximum Forward Voltage Drop Characteristics

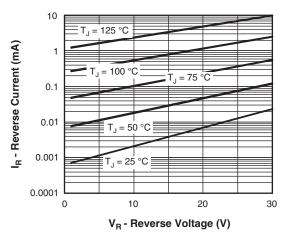


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

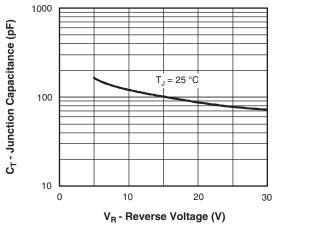
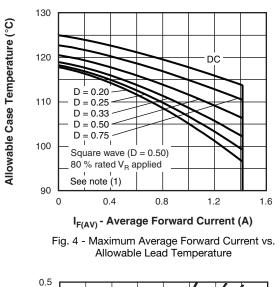
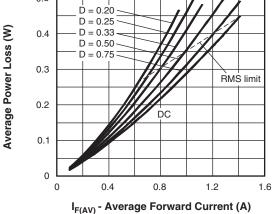


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

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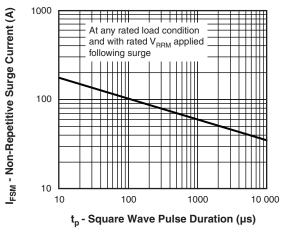


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

Revision: 03-Feb-15

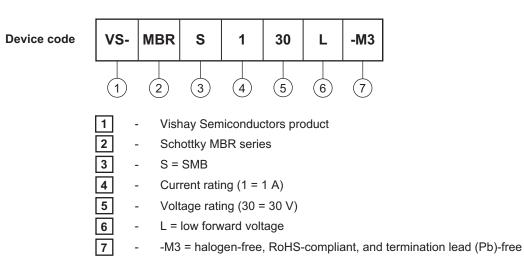
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ORDERING INFORMATION (Example)					
PREFERRED P/N	PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION				
VS-MBRS130L-M3/5BT	5BT	3200	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS		
Dimensions www.vishay.com/doc?95401		
Part marking information	www.vishay.com/doc?95403	
Packaging information	www.vishay.com/doc?95404	

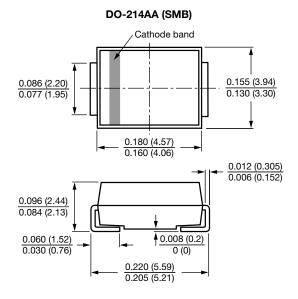


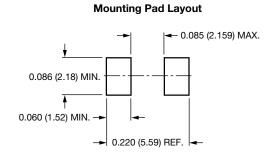
Outline Dimensions

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SMB

DIMENSIONS in inches (millimeters)







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